

Resistivity of Non-Fermi Liquid $\text{U}_2\text{Pt}_2\text{In}$ Under Pressure

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Abstract

Non-Fermi liquid behaviour in single-crystalline $\text{U}_2\text{Pt}_2\text{In}$ has been studied by means of resistivity experiments ($\mathbf{I}||\mathbf{c}$) under hydrostatic pressure ($P < 1.5$ GPa). At ambient pressure the resistivity $\rho(T)$ follows a power law $\rho \sim T^\alpha$ with $\alpha \sim 0.5$. Upon applying pressure α increases. For $P > 1$ GPa a minimum develops in $\rho(T)$. A study of the field dependence of the minimum confirms its magnetic origin. The ratio c/a is proposed as the effective control parameter, rather than the unit cell volume.

Keywords: $\text{U}_2\text{Pt}_2\text{In}$, Non-Fermi liquid, Pressure effects

The intermetallic compound $\text{U}_2\text{Pt}_2\text{In}$ (tetragonal Zr_3Al_2 -type structure) is one of the few stoichiometric compounds known to exhibit non-Fermi liquid (NFL) properties [1] at ambient pressure, as evidenced by a pronounced $c/T \sim \ln T$ contribution to the specific heat below ~ 6 K [2] and a low temperature electrical resistivity described by a power law $\rho \sim T^\alpha$ with $\alpha \sim 1$ for $\mathbf{I}||\mathbf{a}$ and $\alpha \sim 0.5$ for $\mathbf{I}||\mathbf{c}$ [3]. A broad maximum at $T_{\text{max}} = 8$ K in the magnetization measured for $\mathbf{B}||\mathbf{c}$ [3] and a rapid increase below T_{max} of the line width of a dynamic component in the zero-field μSR spectra [2] indicate the presence of short-range magnetic correlations. μSR experiments confirm the absence of (weak) magnetic order. Although the residual resistivity of $\text{U}_2\text{Pt}_2\text{In}$ is quite high ($\rho_0 \sim 100 \mu\Omega\text{cm}$), X-ray [3] and neutron diffraction [4] experiments

carried out on single-crystalline samples rule out the possibility of significant crystallographic disorder (namely intersite exchange). The location of $\text{U}_2\text{Pt}_2\text{In}$ at the border line of magnetic and non-magnetic compounds in a Doniach-type of diagram for the $\text{U}_2\text{T}_2\text{X}$ family [5] suggests the proximity to a quantum critical point as the origin of the non-Fermi liquid behaviour in this compound.

Recently, polycrystalline samples of $(\text{U}_{1-x}\text{Th}_x)_2\text{Pt}_2\text{In}$ were prepared for $x \leq 0.1$ [6] and studied by magnetization and μSR , which showed that Th doping stabilizes the magnetic state in $\text{U}_2\text{Pt}_2\text{In}$ [7]. Assuming that the main role of Th doping is an expansion of the unit cell, applying hydrostatic pressure gives the opportunity to study the effects of a unit cell volume reduction and an eventual recovery of the Fermi liquid state.

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Resistivity measurements in the temperature range 0.3-300 K, under pressures up to 1.5 GPa and magnetic fields up to 8 T, were carried out in bar-shaped single-crystals of $\text{U}_2\text{Pt}_2\text{In}$ using a standard four-probe method. A CuBe piston cylinder-type clamp cell was used with Fluorinert acting as pressure transmitting medium. The pressure values were corrected for an empirical efficiency of 80%.

The zero-pressure resistivity curve for $\mathbf{I} \parallel \mathbf{c}$ follows a power law of the type $\rho \sim T^\alpha$ with $\alpha \sim 0.5$ in the temperature range $0.3 \leq T \leq 2.3$ K [3]. Upon increasing the pressure, α gradually increases for $P < 1$ GPa (fig.1). However, as the pressure is increased further, a minimum in the resistivity develops, which shifts to higher temperatures and becomes more pronounced at higher pressure values: $T_{\min} \sim 1.2$ K at $P = 1.2$ GPa and $T_{\min} \sim 2.1$ K at 1.45 GPa.

In order to investigate whether the observed minimum has a magnetic origin, measurements of $\rho(T)$ under magnetic field ($\mathbf{B} \parallel \mathbf{I}$) were performed at $P = 1.45$ GPa (fig.2). $T_{\min}$ decreases smoothly with the strength of the applied magnetic field: $T_{\min} \sim 1.7$ K for $B = 4$ T and $T_{\min} \sim 1.2$ K for 8 T. Also the minimum becomes less pronounced with field, and is almost suppressed at 8 T. Due to the limited range of temperatures and fields available and the relative uncertainty in determining $T_{\min}$ (especially for the higher fields where the minimum is very shallow), it is not possible at the moment to clearly trace the evolution of $T_{\min}$ with B . The inset on fig.2 shows that the data can be equally fitted with a linear dependence ($B = B_0(1 - T/T_0)$ with $B_0 = 17.0 \pm 1.1$ T and $T_0 = 2.20 \pm 0.05$ K) or a typical antiferromagnetic-like field dependence of the ordering temperature: $B = B_0[1 - (T/T_0)^2]^\beta$ with $B_0 = 9.8 \pm 1.1$ T, $T_0 = 2.14 \pm 0.03$ K and $\beta = 0.82 \pm 0.17$. The field effect on the resistivity curves strongly suggests that $T_{\min}$ has a magnetic origin. Whether $T_{\min}$ is associated with magnetic ordering remains undecided at the moment.

The structure in $\rho(T)$ at $P = 1.45$ GPa resembles in part the one of an antiferromagnetic phase transition of the spin-density wave type, as observed e.g. in the heavy-fermion antiferromagnets URu_2Si_2 ($T_N = 14$ K) [8] and $\text{U}(\text{Pt}_{0.95}\text{Pd}_{0.05})_3$ ($T_N = 5.8$ K) [9]. In these compounds $\rho(T)$ rises below T_N because of the opening of the energy gap. At about $0.9T_N$ $\rho(T)$ develops a local maximum, where below the resistivity drops because of the ordered structure. The data in Fig.1 show that this local maximum is not observed at temperatures $> 0.15T_N$, which might be related to the large residual resistance values of our samples.

The emergence of a magnetic component to $\rho(T)$ upon applying pressure is quite surprising. Applying pressure on a compound at the magnetic instability normally leads to an increase of the control parameter J and brings the compound in the non-ordering Fermi-liquid regime. A possible explanation for this unusual behaviour might be offered by assuming that the control parameter J is not governed by the volume, but by the c/a ratio of the tetragonal unit cell. This is supported by the comparison of the unit cell volumes and c/a ratios of $\text{U}_2\text{Pt}_2\text{In}$ and the antiferromagnets $\text{U}_2\text{Pd}_2\text{In}$ ($T_N = 37$ K) and $\text{U}_2\text{Pt}_2\text{Sn}$ ($T_N = 15$ K) [10]. Whereas the unit-cell volume of $\text{U}_2\text{Pt}_2\text{In}$ is smaller than the one of $\text{U}_2\text{Pd}_2\text{In}$ and larger than the one of $\text{U}_2\text{Pt}_2\text{Sn}$, the c/a ratio is always smaller (for simplicity we have not taken into account the doubling of the crystal structure along the c -axis in single-crystalline $\text{U}_2\text{Pt}_2\text{In}$) [11]. Thus the appearance of magnetic ordering under pressure might be the result of a c/a ratio increase. This in turn requires the compressibility to be anisotropic. X-ray diffraction experiments to determine the lattice parameters of $\text{U}_2\text{Pt}_2\text{In}$ under pressure and of $(\text{U,Th})_2\text{Pt}_2\text{In}$ are underway to investigate this hypothesis.

In summary, we have measured the resistivity of single-crystalline $\text{U}_2\text{Pt}_2\text{In}$ under moderate pressures and conclude that $\text{U}_2\text{Pt}_2\text{In}$ is easily driven away from its non-Fermi-liquid state, as expected for compounds at a quantum critical point.

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References

- [1] See e.g.: Proc. ITP Workshop on Non-Fermi-Liquid Behavior in Solids, Santa Barbara, in J. Phys.: Condens. Matter 8 (1996).
- [2] P. Estrela et al., Physica B 259-261 (1999) 409.
- [3] P. Estrela et al., J. Phys.: Condens. Matter 10 (1998) 9465.
- [4] A. Martin-Martin et al., Phys. Rev. B 59 (1999) 11818.
- [5] V.H. Tran et al., Solid State Commun. 101 (1997) 709.
- [6] L.C.J. Pereira et al., in Proc. 29^{èmes} Journées des Actinides (Luso, Portugal, 1999), p.107.
- [7] P. Estrela et al., to be published.
- [8] T.T.M. Palstra et al., Phys. Rev. B 33 (1986) 6527.
- [9] A. de Visser et al., Physica B 147 (1987) 81.
- [10] L. Havela et al., J. Magn. Magn. Mater. 140-144 (1995) 1367.
- [11] L.C.J. Pereira, PhD Thesis, University of Lisbon, 1998.

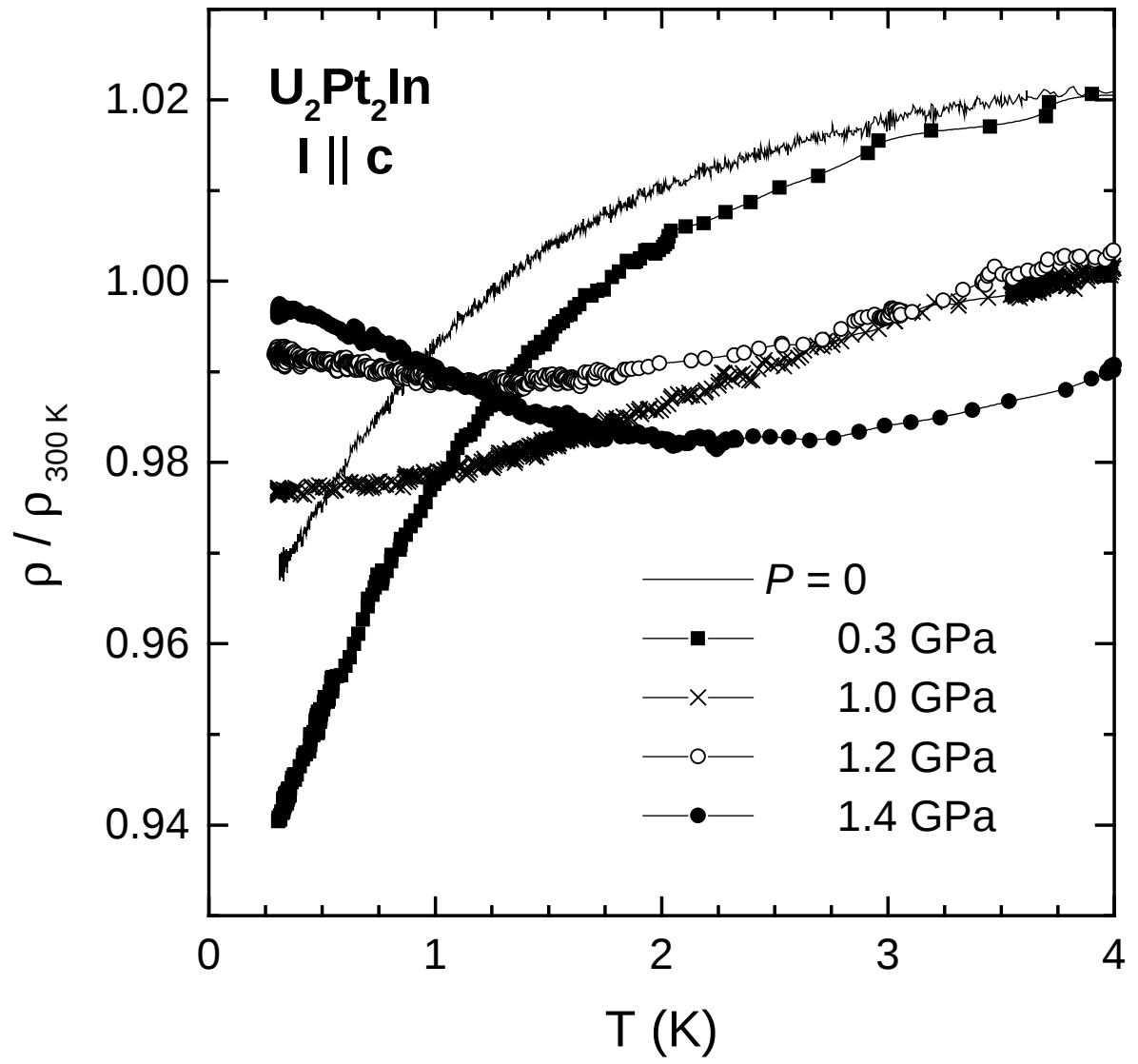


Fig. 1 - Temperature dependence of the electrical resistivity (normalized to the respective room temperature values) at several pressures for I||c in single-crystalline U₂Pt₂In.

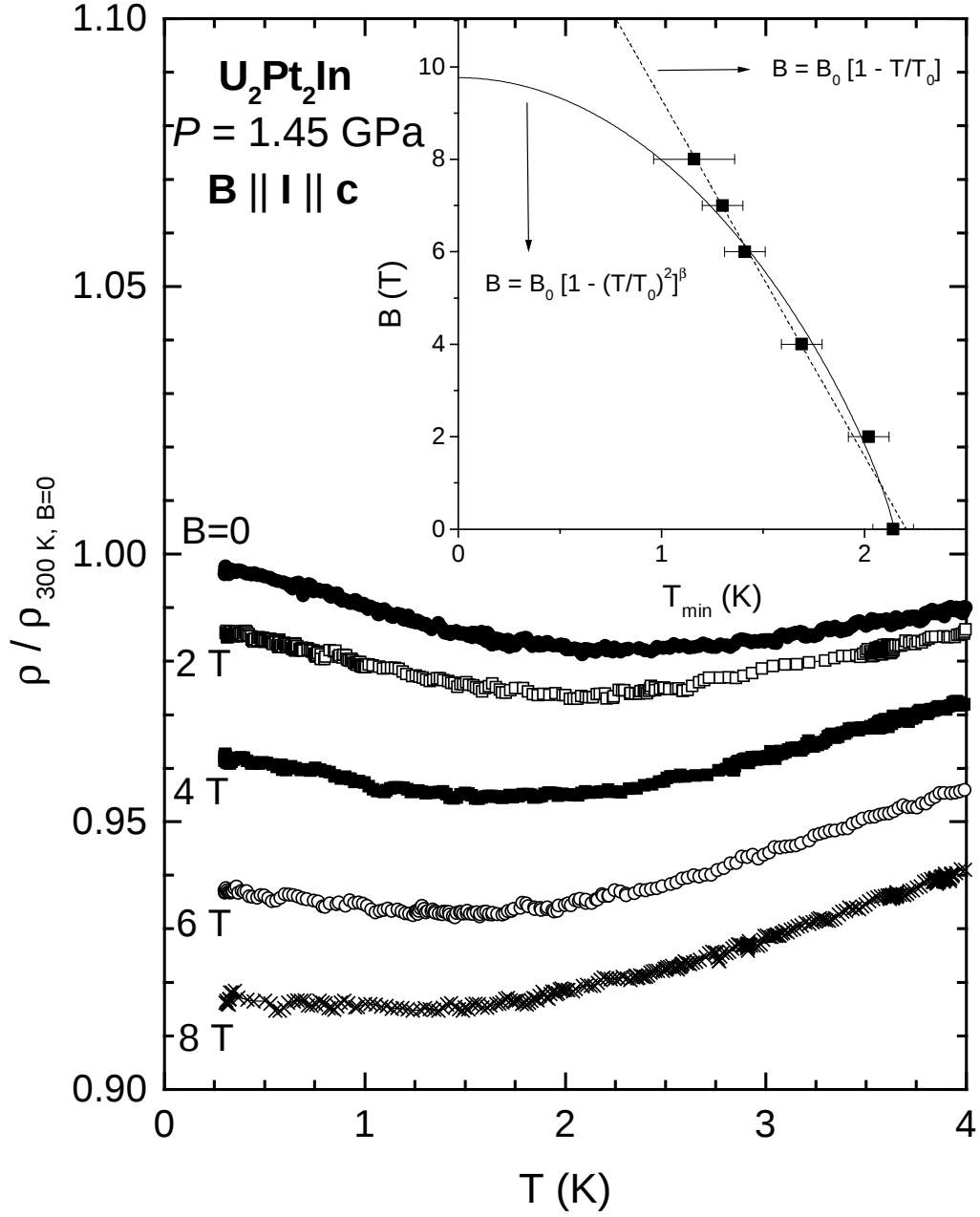


Fig. 2 - Normalized $\rho(T)$ at $P=1.45 \text{ GPa}$ for several magnetic fields applied parallel to the current direction ($\mathbf{B}||\mathbf{I}||\mathbf{c}$). Inset: field dependence of $T_{\min}$ (the lines are fits to the data).